Extension of the Lindhard model, to calculate the "quenching factor" at low energies

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Quenchig Factor

- The amount of electronic excitation produced by a recoiling atom is smaller than that produced by a recoiling electron of the same energy.
- The Q.F is the fraction of energy that IS transformed into ionization energy in a crystal.



- In the direct dark matter searches experiments or in the measurements of the coherent elastic neutrino-nucleus scattering, the signal usually consists in the detection of the low energy (~ 1k eV) of the recoiling target atoms.
- As the experiments have reduced their detection thresholds well below 1 ~ keV, the understanding of the quenching at low energies has become increasingly important.



ϕ can be η or ν

Lindhard Model





- Lindhard after these approximations can deduce this equation .
- Where $t=\epsilon^2 \sin^2(\theta/2)$, f(t) is related to the nuclear cross section scattering.
- Lindhard equation has a problem: the boundary condition at $E \rightarrow 0$, is $\nu(E) \rightarrow E$, so $\nu' \rightarrow 1$ in this limit. But the Integral equation predict $\nu' \rightarrow 0$.
- So the Integral equation can only be solve for energies far from zero.

- Threfore, the equation can be solved making to the Integral equation more raw approximations.
- He found a "reasonable" parametrization from this equation for energies below $\epsilon < 1$.
- This allowed Lindhard to solve numerically his equation for energies $\varepsilon > 1$.
- So this approach doesn't allow us to give a good prediction in low energy regions.



The parametrization doesn't solve the Equation at low energies.

$$\bar{\nu}_l(\epsilon) = \frac{\epsilon}{1 + kg(\epsilon)}$$
$$g(\epsilon) = 3\epsilon^{0.15} + 0.7\epsilon^{0.6} + \epsilon$$

Standar high energy parametrization



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DASK computer 45 kW 3.5 Tons

Summary Lindhard Model and limitations

Extension of Lindhard model

• We introduce the atomic-binding energy, considering the changing the term

$$\bar{\nu}(t/\varepsilon) \to \bar{\nu}(t/\varepsilon - u)$$

- Expand the 1st term in the integral equation $\phi(\epsilon t/\epsilon \Sigma T_{ei})$ to 2nd order in ΣT_{ei} (Probability of electronic stripping process term).
- The lower limit of integration (over dt) can no longer be zero. The min t is now εu. (predicted also by model of scattering of two semi-hard spheres).
- In this model we area going to considere u constant.

• So with this modification we can deduce a new Integral modified equation with atomic-binding energy.

$$-\frac{1}{2}k\varepsilon^{3/2}\bar{\nu}''(\varepsilon) + k\varepsilon^{1/2}\bar{\nu}'(\varepsilon) = \int_{\varepsilon u}^{\varepsilon^2} \frac{dtf(t^{1/2})}{2t^{3/2}} \left[\bar{\nu}(\varepsilon - t/\varepsilon) + \bar{\nu}(t/\varepsilon - u) - \bar{\nu}(\varepsilon))\right]$$

- This equation can be solve numericaly from ε≥u. So the equation predict a threshold energy of u.
- The equation requires the following behavior of the solution.

$$\bar{\nu}_u(\varepsilon) = \begin{cases} \varepsilon + u & \varepsilon < u \\ \varepsilon + u & -g(\varepsilon) & \varepsilon \ge u \end{cases} \quad f_n = \frac{\bar{\eta}}{\varepsilon + \bar{u}} = 1 - \frac{\bar{\nu}}{\varepsilon + \bar{u}}.$$

- The equation admits a solution featuring a "kink" at ε=u (discontinuous 1st derivative).
- We solve the equation by the shooting method pursuing the boundary condition at high energies that $v'' \rightarrow 0$ and for $\epsilon=u$

Alternative good parametrization



- We can implement a good analitical aproximation to solve the Integral equation.
- The idea is to lessen the ionization contribution, substracting a fraccion of the electronic stopping power.

•
$$\eta \rightarrow \eta$$
 - C' - C $\epsilon^{1/2}$

Where C, C' and u are estimated from a fit to the available data.

Results for Si, Ge and Xe.

- We assumed as a first simple model a constant atomic-binding energy (average).
- And also we assume that the k factor, of the electronic stopping power is constant too.

Error of the parametrization 0.6 Error 0.4 0.2 0 Π 10^{-1} Zech о Brian U=350eV **CHICAGO** ANTONELA 10^{-2} Lindhard Model Numeric U=2\$0eV 10^{-3} 10^{2} E (keV) 10 1

Si





05/26/19

Conclusions

- We have implemented an extension to Lindhard model which predicts a cut off at the binding energy.
- We study this new equation and deduce a numeric algorithm that solve the problem with no need of simplifications.
- Also the model now only required the specifications of k and u to have a QF.
- We think that this QF model can have an important impact in the new upcoming results from dark matter and neutrino experiments.
- Other approach (Sorensen) tried to solve this, but in an incomplete way, that doesn't describe the data available.
- We are going to publish this work very soon.

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